

MOSFETs Silicon N-Channel MOS ( $\pi$ -MOSVII)

# TK25A20D

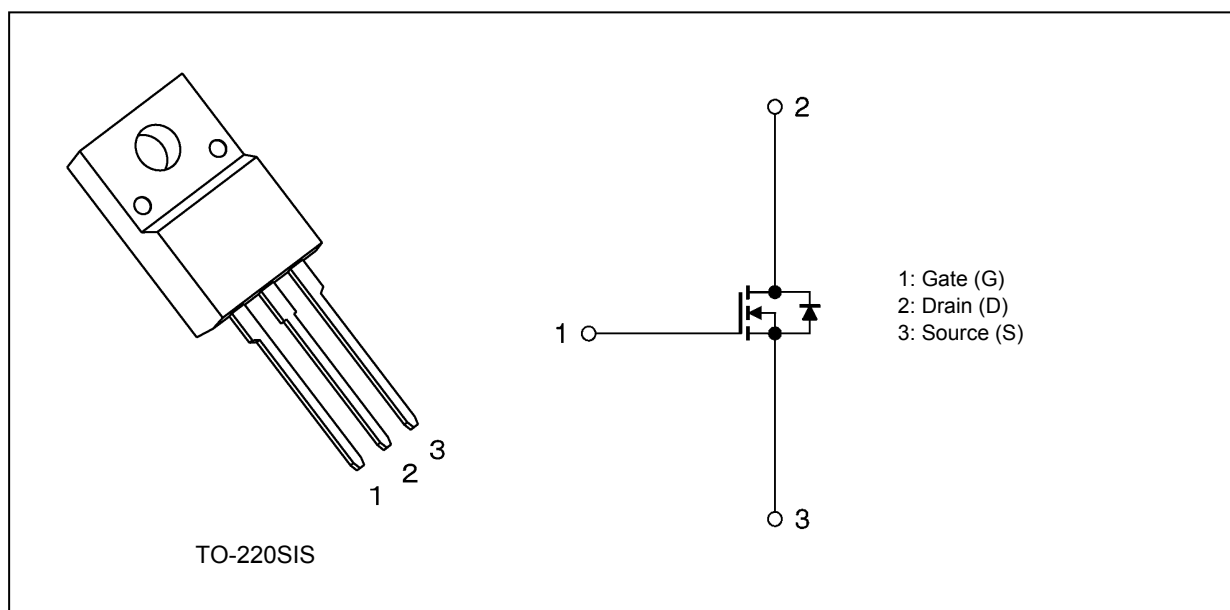
## 1. Applications

- Switching Voltage Regulators

## 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.047 \Omega$  (typ.)
- (2) Low leakage current:  $I_{DSS} = 10 \mu\text{A}$  (max) ( $V_{DS} = 200 \text{ V}$ )
- (3) Enhancement mode:  $V_{th} = 1.5$  to  $3.5 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

## 3. Packaging and Internal Circuit



**4. Absolute Maximum Ratings (Note) ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

| Characteristics                                | Symbol         | Rating     | Unit             |
|--|----------------|------------|------------------|
| Drain-source voltage                           | $V_{DSS}$      | 200        | V                |
| Gate-source voltage                            | $V_{GSS}$      | $\pm 20$   |                  |
| Drain current (DC) (Note 1)                    | $I_D$          | 25         | A                |
| Drain current (pulsed) (Note 1)                | $I_{DP}$       | 100        |                  |
| Power dissipation ( $T_c = 25^\circ\text{C}$ ) | $P_D$          | 45         | W                |
| Single-pulse avalanche energy (Note 2)         | $E_{AS}$       | 118        | mJ               |
| Avalanche current (Note 3)                     | $I_{AR}$       | 25         |                  |
| Reverse drain current (DC) (Note 1)            | $I_{DR}$       | 25         |                  |
| Reverse drain current (pulsed) (Note 1)        | $I_{DRP}$      | 100        |                  |
| Channel temperature                            | $T_{ch}$       | 150        | $^\circ\text{C}$ |
| Storage temperature                            | $T_{stg}$      | -55 to 150 |                  |
| Isolation voltage (RMS) ( $t = 1.0\text{ s}$ ) | $V_{ISO(RMS)}$ | 2000       | V                |
| Mounting torque                                | TOR            | 0.6        | N · m            |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

**5. Thermal Characteristics**

| Characteristics                       | Symbol         | Max  | Unit                      |
|---------------------------------------|----------------|------|---------------------------|
| Channel-to-case thermal resistance    | $R_{th(ch-c)}$ | 2.78 | $^\circ\text{C}/\text{W}$ |
| Channel-to-ambient thermal resistance | $R_{th(ch-a)}$ | 62.5 |                           |

Note 1: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$ .

Note 2:  $V_{DD} = 50\text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 0.3\text{ mH}$ ,  $R_G = 25\ \Omega$ ,  $I_{AR} = 25\text{ A}$

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

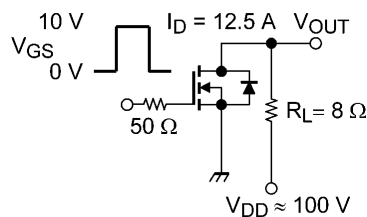
**6. Electrical Characteristics**

**6.1. Static Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

| Characteristics                | Symbol        | Test Condition                                  | Min | Typ.  | Max     | Unit          |
|--------------------------------|---------------|---|-----|-------|---------|---------------|
| Gate leakage current           | $I_{GSS}$     | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | —   | —     | $\pm 1$ | $\mu\text{A}$ |
| Drain cut-off current          | $I_{DSS}$     | $V_{DS} = 200\text{ V}, V_{GS} = 0\text{ V}$    | —   | —     | 10      |               |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$       | 200 | —     | —       | V             |
| Gate threshold voltage         | $V_{th}$      | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$       | 1.5 | —     | 3.5     |               |
| Drain-source on-resistance     | $R_{DS(ON)}$  | $V_{GS} = 10\text{ V}, I_D = 12.5\text{ A}$     | —   | 0.047 | 0.07    | $\Omega$      |

**6.2. Dynamic Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

| Characteristics                | Symbol    | Test Condition   | Min | Typ. | Max | Unit        |
|--------------------------------|-----------|--|-----|------|-----|-------------|
| Input capacitance              | $C_{iss}$ | $V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | —   | 2550 | —   | $\text{pF}$ |
| Reverse transfer capacitance   | $C_{rss}$ |  | —   | 21   | —   |             |
| Output capacitance             | $C_{oss}$ |  | —   | 180  | —   |             |
| Gate resistance                | $r_g$     | $V_{DS} = \text{OPEN}, f = 1\text{ MHz}$                       | —   | 6.3  | —   | $\Omega$    |
| Switching time (rise time)     | $t_r$     | See Figure 6.2.1.  | —   | 73   | —   | ns          |
| Switching time (turn-on time)  | $t_{on}$  |  | —   | 120  | —   |             |
| Switching time (fall time)     | $t_f$     |  | —   | 66   | —   |             |
| Switching time (turn-off time) | $t_{off}$ |  | —   | 360  | —   |             |



Duty  $\leq 1\%$ ,  $t_w = 10\ \mu\text{s}$

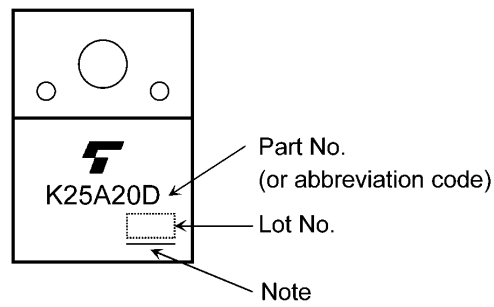
**Fig. 6.2.1 Switching Time Test Circuit**

**6.3. Gate Charge Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

| Characteristics                                 | Symbol    | Test Condition   | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | $Q_g$     | $V_{DD} \approx 160\text{ V}, V_{GS} = 10\text{ V}, I_D = 25\text{ A}$ | —   | 60   | —   | nC   |
| Gate-source charge 1                            | $Q_{gs1}$ |  | —   | 11   | —   |      |
| Gate-drain charge                               | $Q_{gd}$  |  | —   | 22   | —   |      |

**6.4. Source-Drain Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

| Characteristics               | Symbol    | Test Condition  | Min | Typ. | Max  | Unit          |
|-------------------------------|-----------|---|-----|------|------|---------------|
| Diode forward voltage         | $V_{DSF}$ | $I_{DR} = 25\text{ A}, V_{GS} = 0\text{ V}$   | —   | —    | -1.7 | V             |
| Reverse recovery time         | $t_{rr}$  | $I_{DR} = 25\text{ A}, V_{GS} = 0\text{ V}$<br>$-di_{DR}/dt = 100\text{ A}/\mu\text{s}$ | —   | 195  | —    | ns            |
| Reverse recovery charge       | $Q_{rr}$  |   | —   | 1.6  | —    | $\mu\text{C}$ |
| Peak reverse recovery current | $I_{rr}$  |   | —   | 16   | —    | A             |

**7. Marking (Note)****Fig. 7.1 Marking**

Note: A line under a Lot No. identifies the indication of product Labels.

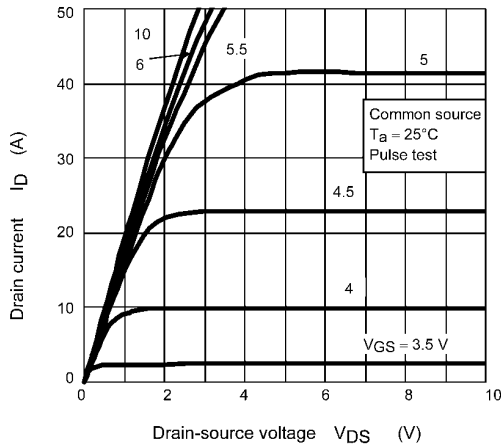
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

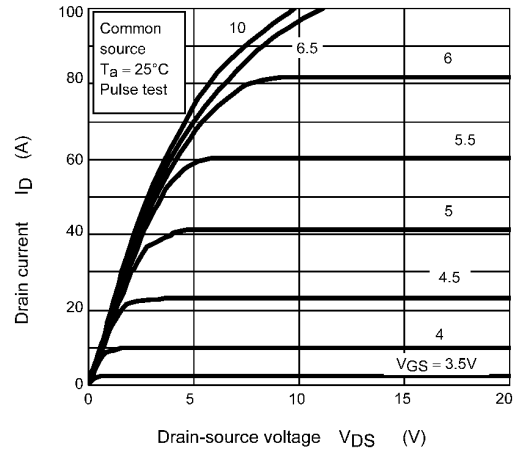
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

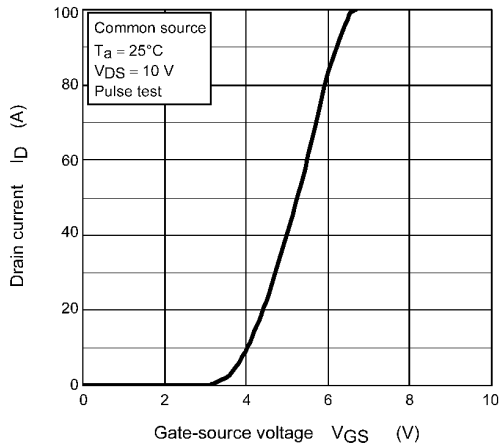
**8. Characteristics Curves (Note)**



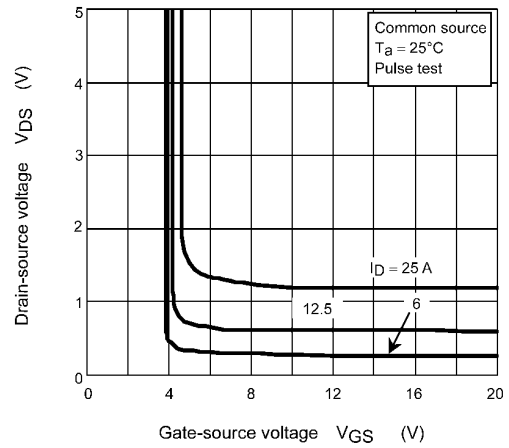
**Fig. 8.1  $I_D - V_{DS}$**



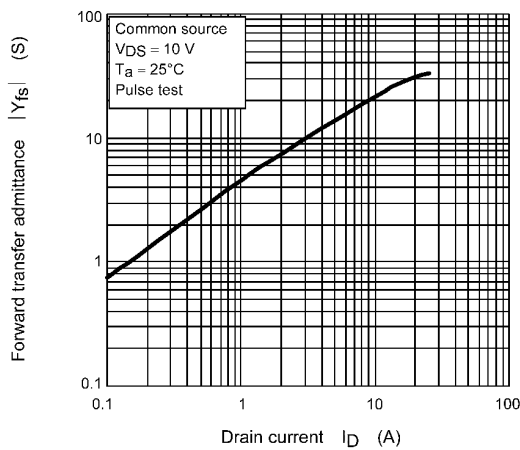
**Fig. 8.2  $I_D - V_{DS}$**



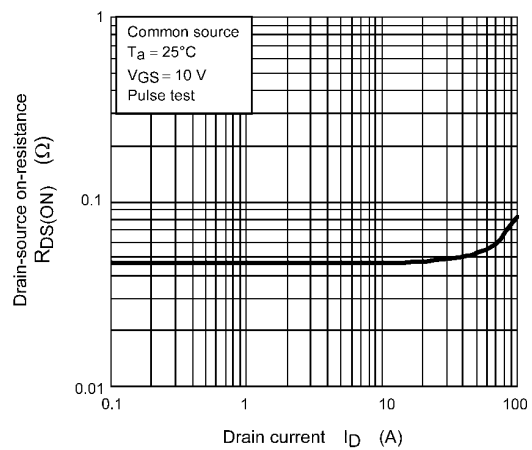
**Fig. 8.3  $I_D - V_{GS}$**



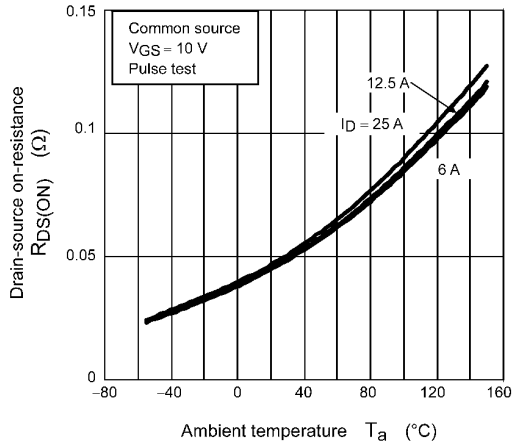
**Fig. 8.4  $V_{DS} - V_{GS}$**



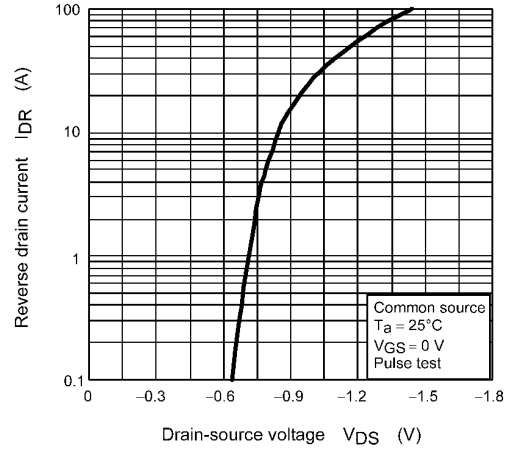
**Fig. 8.5  $|Y_{fs}| - I_D$**



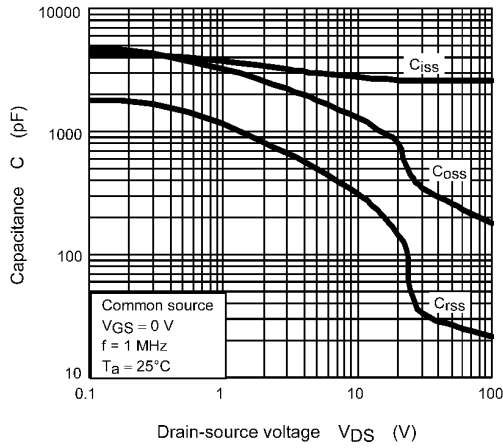
**Fig. 8.6  $R_{DS(ON)} - I_D$**



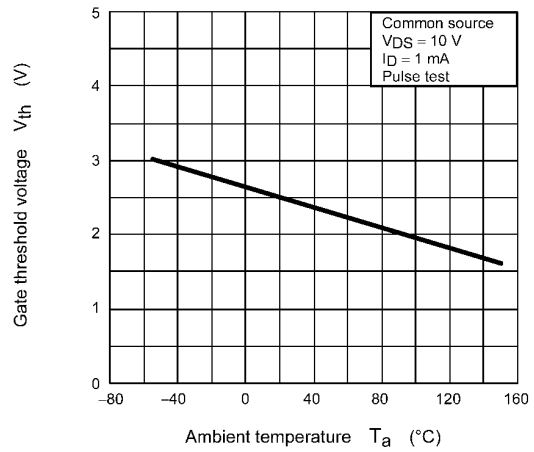
**Fig. 8.7  $R_{DS(ON)} - T_a$**



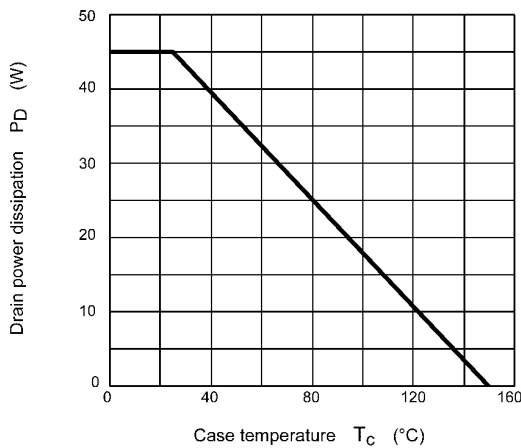
**Fig. 8.8  $I_{DR} - V_{DS}$**



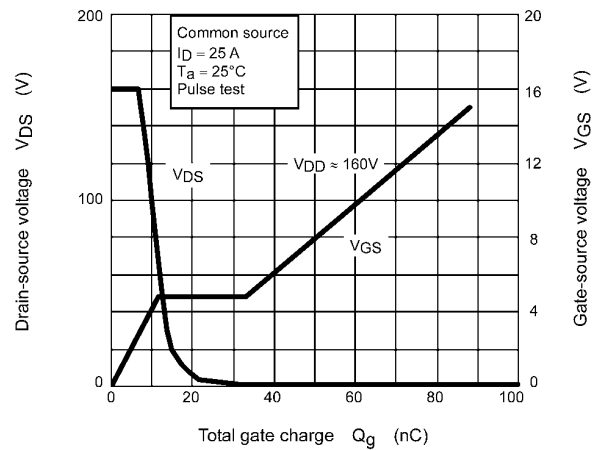
**Fig. 8.9  $C - V_{DS}$**



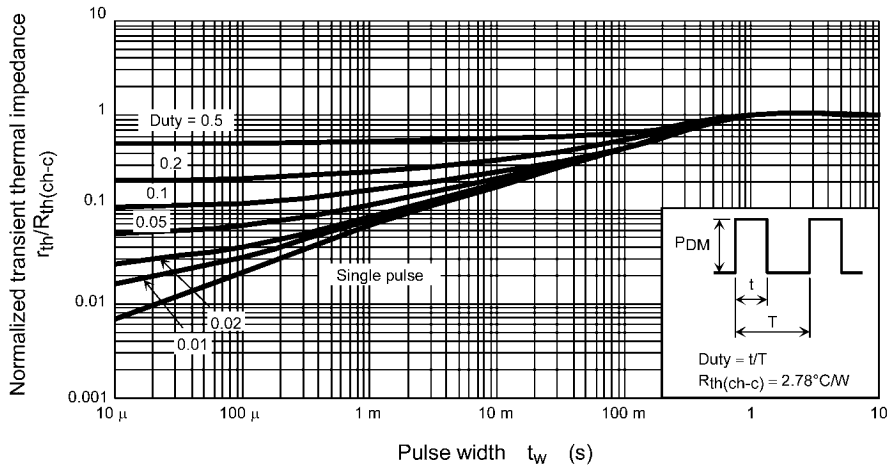
**Fig. 8.10  $V_{th} - T_a$**



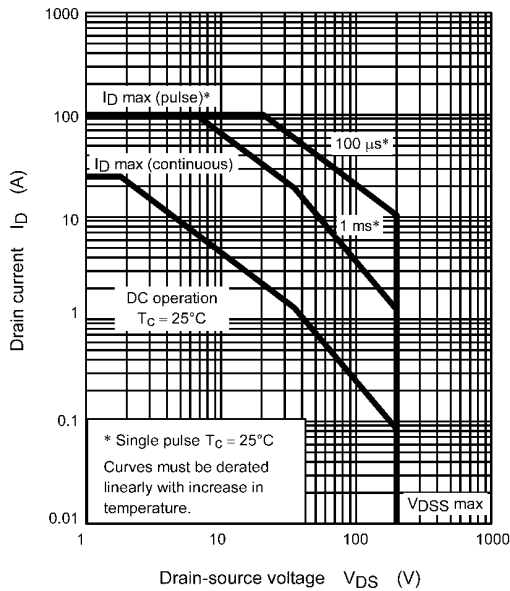
**Fig. 8.11  $P_D - T_c$   
(Guaranteed Maximum)**



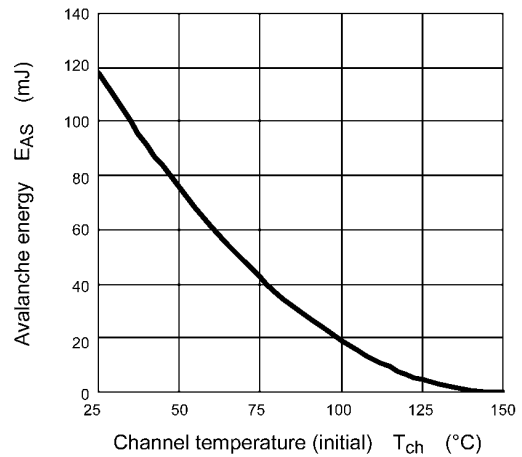
**Fig. 8.12 Dynamic Input/Output Characteristics**



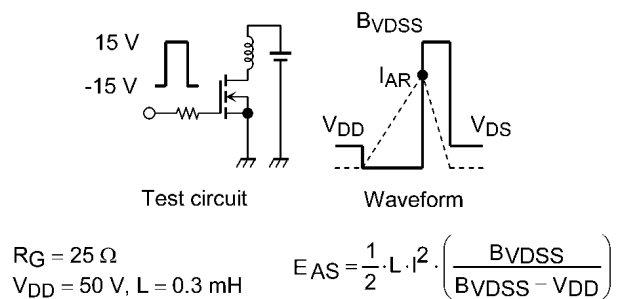
**Fig. 8.13**  $r_{th}/R_{th(ch-c)} - t_w$   
(Guaranteed Maximum)



**Fig. 8.14** Safe Operating Area  
(Guaranteed Maximum)



**Fig. 8.15**  $E_{AS} - T_{ch}$   
(Guaranteed Maximum)

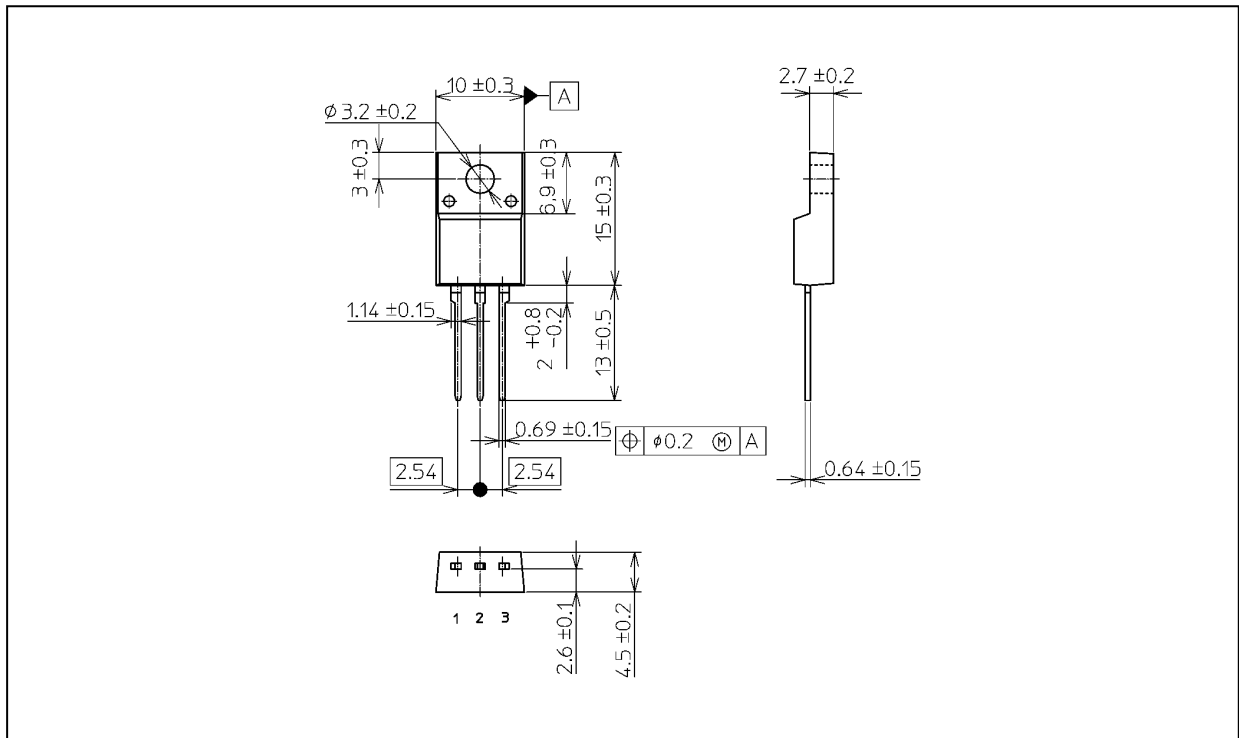


**Fig. 8.16** Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

**Package Dimensions**

Unit: mm



Weight: 1.7 g (typ.)

| Package Name(s)     |
|---------------------|
| JEITA: SC-67        |
| TOSHIBA: 2-10U1S    |
| Nickname: TO-220SIS |

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